# **Dual 2-Input NOR Gate**

# **NL27WZ02**

The NL27WZ02 is a high performance dual 2-input NOR Gate operating from a 1.65 V to 5.5 V supply.

#### **Features**

- $\bullet$  Designed for 1.65 V to 5.5 V  $V_{CC}$  Operation
- 2.5 ns  $t_{PD}$  at  $V_{CC} = 5 \text{ V (typ)}$
- Inputs/Outputs Overvoltage Tolerant up to 5.5 V
- I<sub>OFF</sub> Supports Partial Power Down Protection
- Source/Sink 24 mA at 3.0 V
- Available in US8, UDFN8 and UQFN8 Packages
- Chip Complexity < 100 FETs
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



Figure 1. Logic Symbol



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US8 **US SUFFIX CASE 493** 



**MARKING** 



UDFN8, 1.95x1.0 MU1 SUFFIX CASE 517CA





UDFN8, 1.6x1.0 **MU2 SUFFIX** CASE 517BY





UDFN8, 1.45x1.0 **MU3 SUFFIX** CASE 517BZ





UQFN8. 1.6x1.6 **MQ1 SUFFIX** CASE 523AN





1

UQFN8. 1.4x1.2 MQ2 SUFFIX CASE 523AS



X, XX, XXXX = Specific Device Code = Assembly Location L = Lot Code Υ = Year Code W = Week Code Μ = Date Code = Pb-Free Package

#### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data sheet.

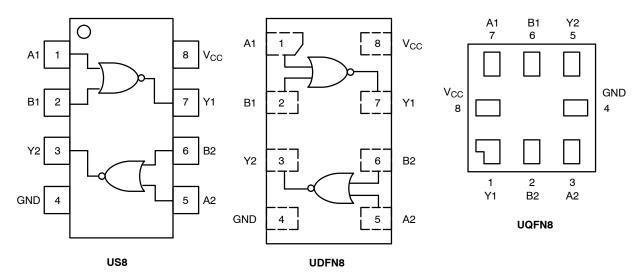


Figure 2. Pinout

# PIN ASSIGNMENT (US8 / UDFN8)

Pin	Function
1	A1
2	B1
3	Y2
4	GND
5	A2
6	B2
7	Y1
8	V <sub>CC</sub>

# PIN ASSIGNMENT (UQFN8)

Pin	Function
1	Y1
2	B2
3	A2
4	GND
5	Y2
6	B1
7	A1
8	V <sub>CC</sub>

## **FUNCTION TABLE**

Inputs		Output
Α	В	Υ
L	L	Н
L	Н	L
Н	L	L
Н	Н	L

H = HIGH Logic Level L = LOW Logic Level

#### **MAXIMUM RATINGS**

Symbol	Characteristics		Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +6.5	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +6.5	V
	DC Output Voltage	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to +6.5 -0.5 to +6.5	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-50	mA
I <sub>OK</sub>	DC Output Diode Current $V_{OUT} < GND$		-50	mA
I <sub>OUT</sub>	DC Output Source/Sink Current		±50	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC Supply Current per Supply Pin or	Ground Pin	±100	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
$T_L$	Lead Temperature, 1 mm from Case f	or 10 secs	260	°C
$T_J$	Junction Temperature Under Bias		+150	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 2)	US8 UQFN8 UDFN8	250 210 231	°C/W
P <sub>D</sub>	Power Dissipation in Still Air	US8 UQFN8 UDFN8	500 595 541	mW
MSL	Moisture Sensitivity		Level 1	-
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	_
V <sub>ESD</sub>	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 1000	V
I <sub>Latchup</sub>	Latchup Performance (Note 4)		± 100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Applicable to devices with outputs that may be tri-stated.
- Applicable to devices with early set that may be the stated.
   Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.
   HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.

  4. Tested to EIA/JESD78 Class II.

### RECOMMENDED OPERATING CONDITIONS

Symbol	Cha	Characteristics		Max	Unit
V <sub>CC</sub>	Positive DC Supply Voltage		1.65	5.5	V
V <sub>IN</sub>	DC Input Voltage		0	5.5	V
V <sub>OUT</sub>	DC Output Voltage	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	0 0 0	V <sub>CC</sub> 5.5 5.5	
T <sub>A</sub>	Operating Temperature Range		-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0 0 0	20 20 10 5	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

#### DC ELECTRICAL CHARACTERISTICS

			V <sub>CC</sub>	T <sub>A</sub> = 25°C			-55°C ≤ T <sub>A</sub> ≤ 125°C		
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Units
V <sub>IH</sub>	High-Level Input		1.65 to 1.95	0.65 V <sub>CC</sub>	_	_	0.65 V <sub>CC</sub>	-	V
	Voltage		2.3 to 5.5	0.70 V <sub>CC</sub>	-	-	0.70 V <sub>CC</sub>	-	
$V_{IL}$	Low-Level Input		1.65 to 1.95	-	-	0.35 V <sub>CC</sub>	-	0.35 V <sub>CC</sub>	V
	Voltage		2.3 to 5.5	-	-	0.30 V <sub>CC</sub>	-	0.30 V <sub>CC</sub>	
Vон	High-Level Output Voltage	$\begin{split} V_{IN} &= V_{IH} \text{ or } V_{IL} \\ I_{OH} &= -100  \mu\text{A} \\ I_{OH} &= -4 \text{ mA} \\ I_{OH} &= -8 \text{ mA} \\ I_{OH} &= -12 \text{ mA} \\ I_{OH} &= -16 \text{ mA} \\ I_{OH} &= -24 \text{ mA} \\ I_{OH} &= -32 \text{ mA} \end{split}$	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	V <sub>CC</sub> - 0.1 1.29 1.9 2.2 2.4 2.3 3.8	V <sub>CC</sub> 1.4 2.1 2.4 2.7 2.5 4.0	- - - - -	V <sub>CC</sub> - 0.1 1.29 1.9 2.2 2.4 2.3 3.8	- - - - -	٧
V <sub>OL</sub>	Low-Level Output Voltage	$\begin{split} V_{IN} &= V_{IH} \text{ or } V_{IL} \\ I_{OL} &= 100  \mu\text{A} \\ I_{OL} &= 4 \text{ mA} \\ I_{OL} &= 8 \text{ mA} \\ I_{OL} &= 12 \text{ mA} \\ I_{OL} &= 16 \text{ mA} \\ I_{OL} &= 24 \text{ mA} \\ I_{OL} &= 32 \text{ mA} \end{split}$	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	- - - -	- 0.08 0.2 0.22 0.28 0.38 0.42	0.1 0.24 0.3 0.4 0.4 0.55 0.55		0.1 0.24 0.3 0.4 0.4 0.55 0.55	٧
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	1.65 to 5.5	-	-	±0.1	-	±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0	-	_	1.0	-	10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	-	_	1.0	-	10	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

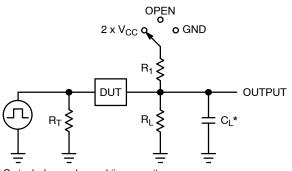
### **AC ELECTRICAL CHARACTERISTICS**

				7	Γ <sub>A</sub> = 25°(		T <sub>A</sub> = -55	to 125°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Test Conditions	Min	Тур	Max	Min	Max	Units
t <sub>PLH</sub> ,	Propagation Delay,	1.65 to 1.95	C <sub>L</sub> = 15 pF	-	7.4	9.5	-	9.7	ns
t <sub>PHL</sub>	(A or B) to Y	2.3 to 2.7	$R_L = 1 M\Omega$ $R_1 = Open$	-	3.3	5.4	-	5.8	
		3.0 to 3.6		-	2.6	3.9	-	4.3	
		4.5 to 5.5		-	1.9	3.1	-	3.3	
		3.0 to 3.6	C <sub>L</sub> = 50 pF,	-	3.2	4.8	-	5.2	
		4.5 to 5.5	$R_L = 500 \Omega, R_1 = Open$	-	2.5	3.7	-	4.0	

#### **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Condition	Typical	Units
C <sub>IN</sub>	Input Capacitance	$V_{CC} = 5.5 \text{ V}, V_{IN} = 0 \text{ V or } V_{CC}$	2.5	pF
C <sub>OUT</sub>	Output Capacitance	$V_{CC} = 5.5 \text{ V}, V_{IN} = 0 \text{ V or } V_{CC}$	2.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 5)	10 MHz, $V_{CC}$ = 3.3 V, $V_{IN}$ = 0 V or $V_{CC}$ 10 MHz, $V_{CC}$ = 5.5 V, $V_{IN}$ = 0 V or $V_{CC}$	9 11	pF

<sup>5.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.



Test	Switch Position	C <sub>L</sub> , pF	$R_L, \Omega$	R <sub>1</sub> , Ω	
t <sub>PLH</sub> / t <sub>PHL</sub>	Open	See AC Characteristics Table			
t <sub>PLZ</sub> / t <sub>PZL</sub>	2 x V <sub>CC</sub>	50	500	500	
t <sub>PHZ</sub> / t <sub>PZH</sub>	GND	50	500	500	

X = Don't Care

 $C_L$  includes probe and jig capacitance  $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50  $\Omega)$ 

f = 1 MHz

Figure 3. Test Circuit

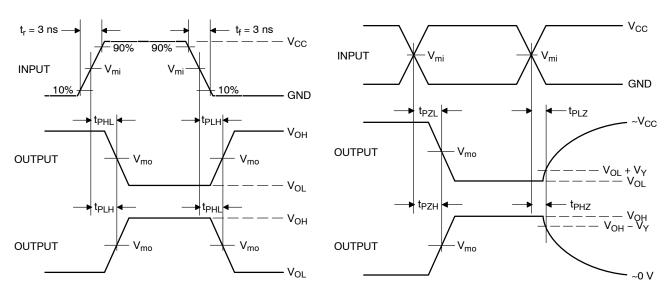


Figure 4. Switching Waveforms

		V <sub>r</sub>		
V <sub>CC</sub> , V	V <sub>mi</sub> , V	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub> , t <sub>PZH</sub> , t <sub>PHZ</sub>	V <sub>Y</sub> , V
1.65 to 1.95	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.15
2.3 to 2.7	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.15
3.0 to 3.6	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3
4.5 to 5.5	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3

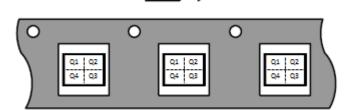
#### **DEVICE ORDERING INFORMATION**

Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping <sup>†</sup>
NL27WZ02USG	US8	L3	Q4	3000 / Tape & Reel
NL27WZ02MQ1TCG (In Development)	UQFN8, 1.6 x 1.6, 0.5P	TBD	TBD	3000 / Tape & Reel
NL27WZ02MU1TCG	UDFN8, 1.95 x 1.0, 0.5P	AL	Q4	3000 / Tape & Reel
NL27WZ02MU1TWG	UDFN8, 1.95 x 1.0, 0.5P	AM	Q1	3000 / Tape & Reel
NL27WZ02MU3TCG	UDFN8, 1.45 x 1.0, 0.35P	J	Q4	3000 / Tape & Reel
NL27WZ02MU2TCG	UDFN8, 1.6 x 1.0, 0.4P	АН	Q4	3000 / Tape & Reel
NL27WZ02MQ2TCG (In Development)	UQFN8, 1.4 x 1.2, 0.4P	TBD	TBD	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### Pin 1 Orientation in Tape and Reel

### **Direction of Feed**



<sup>\*</sup>NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

R R R R

В



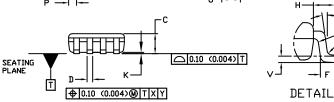


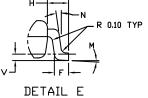
**DATE 01 SEP 2021** 

#### NOTES:

DETAIL E

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSION, OR GATE BURR. MOLD FLASH, PROTRUSION, OR GATE BURR SHALL NOT EXCEED 0.14 (0.0055°) PER SIDE.
- DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH AND PROTRUSION SHALL NOT EXCEED 0.14 (0.0055") PER SIDE.
- LEAD FINISH IS SOLDER PLATING WITH THICKNESS OF 0.0076-0.0203 MM (0.003-0.008").
- ALL TOLERANCE UNLESS OTHERWISE SPECIFIED ±0.0508 MM (0.002").

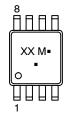




8X 0.30—  <del> </del>
8x 0.68
1 0 🕪 📗 📗
0,50 →
RECOMMENDED * MOUNTING FOOTPRINT
For additional information on our Pb-Free

	MILLIMETERS		INCHES	
DIM	MIN.	MAX.	MIN.	MAX.
Α	1.90	2.10	0.075	0.083
В	2.20	2.40	0.087	0.094
C	0.60	0.90	0.024	0.035
D	0.17	0.25	0.007	0.010
F	0.20	0.35	0.008	0.014
G	0.50 BSC		0.020 BSC	
H	0.40 REF		0.016 REF	
J	0.10	0.18	0.004	0.007
К	0.00	0.10	0.000	0.004
L	3.00	3.25	0.118	0.128
W	0*	6*	0*	6*
N	0*	10*	0*	10*
Э	0.23	0.34	0.010	0.013
R	0.23	0.33	0.009	0.013
2	0.37	0.47	0.015	0.019
υ	0.60	0.80	0.024	0.031
<b>V</b>	0.12	BSC	0.005	BSC

#### **GENERIC MARKING DIAGRAM\***



XX = Specific Device Code = Date Code

M

= Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	US8		PAGE 1 OF 1

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**TOP VIEW** 

**SIDE VIEW** 

**BOTTOM VIEW** 

PIN ONE REFERENCE

0.10 C

|△| 0.10 | C

0.05 C

C 0.05

e/2

2X 🗀



UDFN8, 1.6x1, 0.4P CASE 517BY-01 **ISSUE O** 

C SEATING PLANE

0.10 M C A B

0.05 M C NOTE 3

AB

Ε

<u></u> 7х L

**DATE 18 MAY 2011** 

#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN
- 0.15 AND 0.20 MM FROM TERMINAL TIP. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.45	0.55	
A1	0.00	0.05	
А3	0.13 REF		
b	0.15	0.25	
D	1.60 BSC		
Е	1.00 BSC		
е	0.40 BSC		
L	0.25	0.35	
L1	0.30	0.40	

#### **GENERIC MARKING DIAGRAM\***



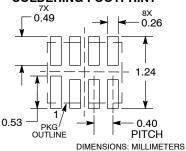
X = Specific Device Code

M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " ■", may or may not be present.

#### **RECOMMENDED SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

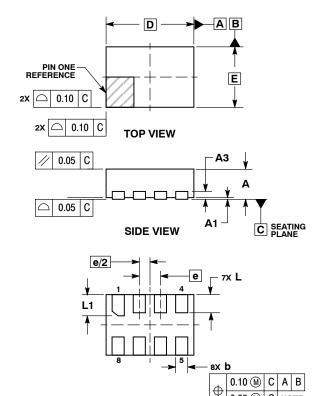
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DESCRIPTION:	UDFN8, 1.6X1, 0.4P		PAGE 1 OF 1

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UDFN8, 1.45x1, 0.35P CASE 517BZ-01 **ISSUE O** 

**DATE 18 MAY 2011** 



**BOTTOM VIEW** 

#### NOTES:

- DIMENSIONING AND TOLERANCING PER
  ASME Y14.5M. 1994.
- CONTROLLING DIMENSION: MILLIMETERS. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN
- 0.15 AND 0.20 MM FROM TERMINAL TIP.
  4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

	MULIMETERO		
	MILLIMETERS		
DIM	MIN	MAX	
Α	0.45	0.55	
A1	0.00	0.05	
А3	0.13 REF		
b	0.15	0.25	
D	1.45	BSC	
Е	1.00 BSC		
е	0.35 BSC		
L	0.25	0.35	
L1	0.30	0.40	

#### **GENERIC MARKING DIAGRAM\***



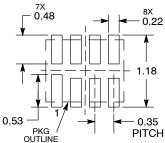
X = Specific Device Code

M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " ■", may or may not be present.

#### RECOMMENDED **SOLDERING FOOTPRINT\***



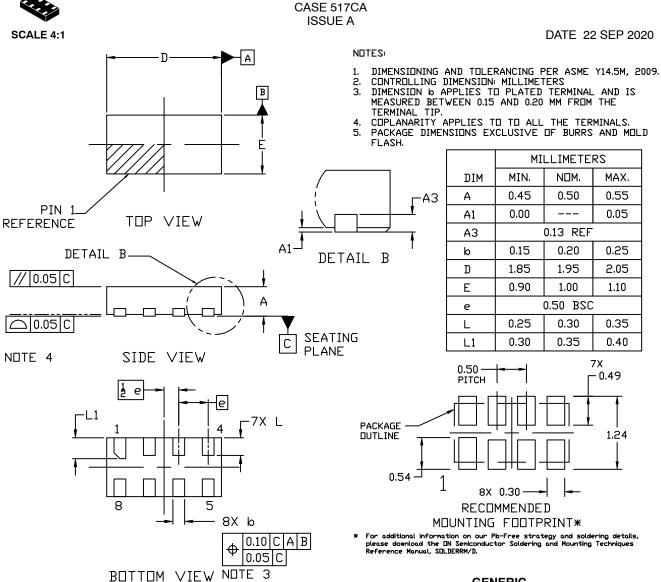
DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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0.05 M C NOTE 3

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UDFN8, 1.95x1.0, 0.5P

# GENERIC MARKING DIAGRAM\*



X = Specific Device CodeM = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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